



IC FOR TELECOMMUNICATIONS EQUIPMENT

ICs FOR DATA BANKS

Model No.	Features	Function						Supply voltage (V)	Package
		Power supply	Display	Auto power off	Secret function	Calculation function	Others		
LI350471	Memory of 26 persons' names and telephone numbers	Battery	5 × 5-dot × 12-digit 7-segment × 12-digit	●	●	10-digit 1 memory	3 modes (telephone, memo, calculator)	2.5 to 3.4	80QFP
LI350361	Memory of 60 persons' names and telephone numbers	Battery	5 × 5-dot × 12-digit 7-segment × 12-digit	●	●	10-digit 1 memory	4 modes (telephone, memo, clock, calculator)	2.5 to 3.4	100QFP
LI350941	Memory of 98 persons' names and telephone numbers	Battery	5 × 7-dot × 12-digit 7-segment × 12-digit	●	●	10-digit 1 memory	5 modes (telephone, memo, scheduler, clock, calculator)	2.5 to 3.4	100QFP
SM3503	Microcomputer for data bank	Battery	60-segment × 8-common	●		Built-in clock function, buzzer output, ROM: 6 k × 23-bit, RAM: 1 k × 8-bit		2.5 to 3.4	100QFP
SM3504	Microcomputer for data bank	Battery	60-segment × 8-common	●		Built-in clock function, buzzer output, ROM: 6 k × 23-bit, RAM: 512 × 8-bit		2.5 to 3.4	80QFP
SM3507	Microcomputer for data bank	Battery	48-segment × 8-common	●		Built-in clock function, buzzer output, I/O 8-bit ROM: 6 k × 23-bit, RAM: 512 × 8-bit		2.5 to 3.4	80QFP
SM3511	Microcomputer for data bank	Battery	98-segment × 32-common	●		Built-in carrier wave signal generator for infrared communication ROM: 24 k × 23-bit, RAM: 512 × 8-bit, external memory: 16 M-byte × 4		3.8 to 6.0	208QFP*
SM3512	Microcomputer for data bank	Battery	60-segment × 9-common	●		Built-in clock function, buzzer output, I/O 8-bit ROM: 8 k × 23-bit, RAM: 8 k × 8-bit		2.5 to 3.4	100QFP
SM3513	Microcomputer for data bank	Battery	74-segment × 32-common	●		Built-in carrier wave signal generator for infrared communication ROM: 24 k × 23-bit, RAM: 512 × 8-bit, external memory 16 M-byte × 4		3.8 to 6.0	160QFP*
SM3514	Microcomputer for data bank	Battery	60-segment × 8-common	●		Built-in clock function, buzzer output ROM: 8 k × 23-bit, RAM: 512 × 8-bit		2.5 to 3.4	100QFP
SM3515	Microcomputer for data bank	Battery	60-segment × 8-common	●		Built-in clock function, buzzer output ROM: 12 k × 23-bit, RAM: 512 × 8-bit		2.5 to 3.4	100QFP
SM3517	Microcomputer for data bank	Battery	60-segment × 9-common	●		Built-in clock function, buzzer output, I/O 8-bit ROM: 8 k × 23-bit, RAM: 2k × 8-bit, external memory 32k-byte		2.5 to 3.4	100QFP*
SM3518	Microcomputer for data bank	Battery	74-segment × 16-common	●		Built-in carrier wave signal generator for infrared communication ROM: 12 k × 23-bit, RAM: 3k × 8-bit, external memory 1M-byte × 3		2.7 to 5.5	128QFP*

●: Yes *: Test sample only

ICs FOR CALCULATORS

Digit	Model No.	Function					Supply voltage (V)	Package
		Memory	Power supply	Auto power off	Punctuation	Others		
8	LI3150/Z	1	Ba/SB	●	—	$\sqrt{\quad}$, %	1.5	40SSOP
	LI3151/Z	1	Ba/SB	●	—	GPM, %	1.5	40SSOP
	LI3152/Z	1	SB	—	—	$\sqrt{\quad}$, %	1.5	40SSOP
	LI3154	1	Ba/SB	Pin selectable	●	$\sqrt{\quad}$, MU key, %, Memory hold	1.5	40SSOP
	LI3155	1	Ba/SB	Pin selectable	●	High-speed type of LI3154 (twice the operation speed)	1.5	40SSOP
10	LI31692/R	1	Ba/SB	Pin selectable	●	$\sqrt{\quad}$, %	1.5	56QFP
	LI31693/R	1	Ba/SB	Pin selectable	●	MU key, %	1.5	56QFP
	LI3160	1	SB	—	●	TAB (A, 0, 2, 3, F), 5/4 function, MU key, \downarrow (round)	1.5	60QFP
10/12	LI31683/R	2	Ba/SB	●	●	TAB(A,0,1,2,3,F), 5/4 function, \downarrow (round), 00key, 2 key roll over, GT, MU key, $\sqrt{\quad}$, %, \rightarrow (shift)	1.5	80QFP
14	LI3184	2	Ba/SB	●	●	TAB(A,0,1,2,3,4,6,F), 5/4 function, \downarrow (round), 00key, 2 key roll over, GT, TAX, MU key, $\sqrt{\quad}$, %, \rightarrow (shift)	1.5	56QFP

ICs FOR SCIENTIFIC CALCULATORS*1

Digit	Model No.	Function					Supply voltage (V)	Package
		Memory	Power supply	Auto power off	Scientific calculation	Others		
10	LI3301A/AR	3	Ba	●	46	8-digit mantissa, 2-digit exponents	3.0	48QFP

●: Yes Ba: Dry battery SB: Solar battery

*1 Commonly known as ESR (Electric Slide Rule)